TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

# 2SD1160

## Switching Applications Suitable for Motor Drive Applications

- High DC current gain
- Low saturation voltage:  $V_{CE}$  (sat) = 0.6 V (max) ( $I_{C}$  = 2A,  $I_{B}$  = 40 mA)
- Built-in free wheel diode

#### Absolute Maximum Ratings (Ta = 25°C)

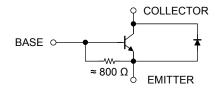
Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	50	V	
Collector-emitter voltage		V <sub>CEO</sub>	20	V	
Emitter-base voltage		V <sub>EBO</sub>	6	V	
Collector current	DC	IC	2	Α	
	Pulse	I <sub>CP</sub>	4		
Diode forward surge current (t = 1 s)		I <sub>FP</sub>	1	Α	
Collector power dissipation	Ta = 25°C	D	1	W	
	Tc = 25°C	P <sub>C</sub>	10		
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the

Weight: 0.36 g (typ.) reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are

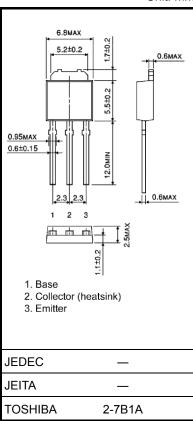
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Equivalent Circuit**



within the absolute maximum ratings.

Unit: mm



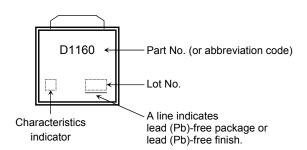
## Electrical Characteristics (Ta = 25°C)

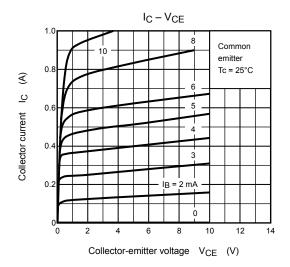
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 50 V, I <sub>E</sub> = 0	_	_	1	μΑ
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0	2.5	6.25	15	mA
Collector-emitter sustaining voltage	V <sub>CEO</sub> (SUS)	I <sub>C</sub> = 20 mA, L = 40 mH	20	_	-	٧
DC current gain	h <sub>FE (1)</sub> (Note)	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 1 A	100	1	300	
	h <sub>FE (2)</sub>	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 2 A	60	_	ı	
Collector emitter saturation voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> = 2 A, I <sub>B</sub> = 40 mA	_	0.4	0.6	V
Base-emitter saturation voltage	V <sub>BE</sub> (sat)	I <sub>C</sub> = 2 A, I <sub>B</sub> = 40 mA	_	_	1.5	V
Emitter-collector forward voltage	V <sub>ECF</sub>	I <sub>E</sub> = 1 A, I <sub>B</sub> = 0	_	_	2.0	٧

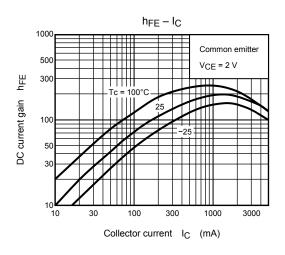
Note: h<sub>FE (1)</sub> classification O: 100 to 200, Y: 150 to 300

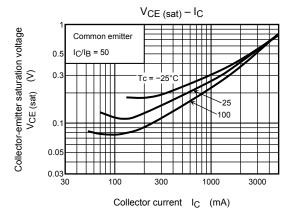
Classification	Min	Max	
2SD1160-O	100	200	
2SD1160-Y	150	300	

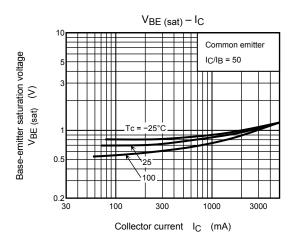
### Marking

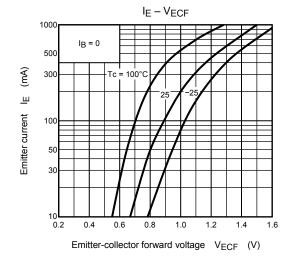


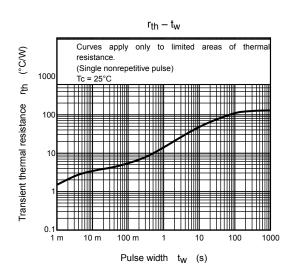


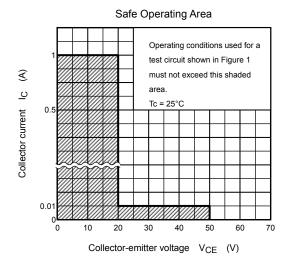












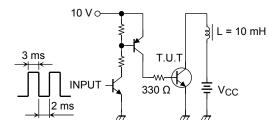
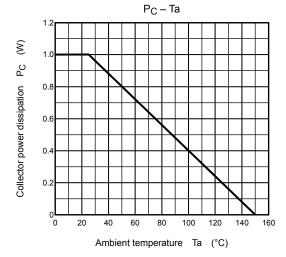


Figure 1 Safe Operating Area Test Circuit



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